TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX16240FT

Low-Voltage 16-Bit Bus Buffer (inverted) with 5-V Tolerant Inputs and Outputs

The TC74LCX16240FT is a high-performance CMOS 16-bit bus buffer. Designed for use in 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

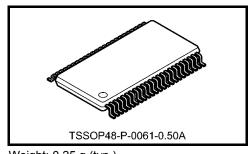
The device is designed for low-voltage (2.5-V or 3.3-V) V_{CC} applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

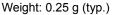
This device is inverting 3-state buffer having four active-low output enables. It can be used as four 4-bit buffers two 8-bit buffers or one 16-bit buffer. When the \overline{OE} input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V
- High-speed operation: t_{pd} = 4.5 ns (max) (V_{CC} = 3.0 to 3.6 V)
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Package: TSSOP
- Power-down protection provided on all inputs and outputs





Pin Assignment (top view)

			1	
10E	1	\bigcirc	48	20E
$1\overline{Y}1$	2		47	1A1
1¥2	3		46	1A2
GND	4		45	GND
1 7 3	5		44	1A3
$1\overline{Y}4$	6		43	1A4
V _{CC}	7		42	V _{CC}
2 <u>7</u> 1	8		41	2A1
2¥2	9		40	2A2
GND	10		39	GND
2¥3	11		38	2A3
$2\overline{Y}4$	12		37	2A4
3 7 1	13		36	3A1
3 7 2	14		35	3A2
GND	15		34	GND
3 7 3	16		33	3A3
3 7 4	17		32	3A4
V _{CC}	18		31	V _{CC}
$4\overline{Y}1$	19		30	4A1
4 <u>7</u> 2	20		29	4A2
GND	21		28	GND
4 7 3	22		27	4A3
$4\overline{Y}4$	23		26	4A4
40E	24		25	30E
			1	

IEC Logic Symbol

10E	1	EN1 EN2 EN3 EN4					
1A1 — 1A2 — 1A3 —	47 46 44		1	17		2 3 5	- 1¥1 - 1¥2 - 1¥3
1A3 1A4 — 2A1 —	43 41		1	2▽	 / /	6 8	- 1¥4 - 2¥1
2A2 — 2A3 —	40 38 37					9 11 12	$2\overline{Y}2$ $2\overline{Y}3$
2A4 — 3A1 — 3A2 —	36 35		1	3▽		13 14	- 2¥4 - 3¥1 - 3¥2
3A3 — 3A4 —	33 32				 / /	16 17	- 3 <u>7</u> 3 - 3 <u>7</u> 4
4A1 — 4A2 — 4A3 —	30 29 27		1	4▽		19 20 22	- 4 <u>7</u> 1 - 4 <u>7</u> 2 - 4 <u>7</u> 3
4A4 —	26					23	$-4\overline{Y}4$

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Truth Table

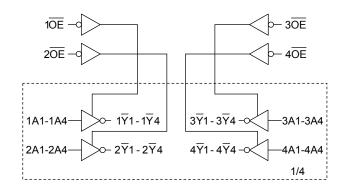
Inp	Outputs	
10E 1A1-1A4		$1\overline{Y}1 - 1\overline{Y}4$
L	L	н
L	Н	L
Н	Х	Z

Inp	Outputs	
20E	20E 2A1-2A4	
L	L	Н
L	н	L
Н	Х	Z

Inp	Outputs	
30E 3A1-3A4		3 7 1-3 7 4
L	L	Н
L	Н	L
Н	Х	Z

Inp	Outputs	
40E	4A1-4A4	$4\overline{Y}1-4\overline{Y}4$
L	L	Н
L	н	L
Н	Х	Z

System Diagram



X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	–0.5 to 6.0	V
Input voltage	V _{IN}	–0.5 to 7.0	V
Output voltage		-0.5 to 7.0 (Note 2)	V
Output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	v
Input diode current	I _{IK}	-50	mA
Output diode current	IOK	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	400	mW
DC V_{CC}/ground current per supply pin	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vee	2.0 to 3.6	V
Fower supply voltage	v CC	V _{CC} 2.0 to 3.6 V _{IN} 0 to 5.5 V _{OUT} 0 to 5.5 (Note 3) 0 to V _{CC} (Note 4) ±24 (Note 5) I _{OH} /I _{OL} ±12 (Note 6) ±8 (Note 7) T _{opr}	v
Input voltage	V _{IN}	0 to 5.5	V
	Vour	0 to 5.5 (Note 3)	V
Output voltage	VOUT	0 to V_{CC} (Note 4)	v
		±24 (Note 5)	
Output current	I _{OH} /I _{OL}	±12 (Note 6)	mA
		±8 (Note 7)	
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

- Note 2: Data retention only
- Note 3: Output in OFF state
- Note 4: High or low state
- Note 5: $V_{CC}=$ 3.0 to 3.6 V $\,$
- Note 6: $V_{CC} = 2.7$ to 3.0 V
- Note 7: $V_{CC} = 2.3$ to 2.7 V
- Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

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Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characterist	ics	Symbol	Test Co	ondition		Min	Max	Unit
					V _{CC} (V)			0
	H-level	VIH			2.3 to 2.7	1.7	_	
Input voltage		VН			2.7 to 3.6	2.0	_	V
Input voltage	L-level	Ma			2.3 to 2.7	_	0.7	v
	L-IEVEI	VIL	VIL —		2.7 to 3.6	_	0.8	
				I _{OH} = -100 μA	2.3 to 3.6	V _{CC} -0.2	_	
				$I_{OH} = -8 \text{ mA}$	2.3	1.8	_	
	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -12 mA	2.7	2.2	_	V
Output voltage				I _{OH} = -18 mA	3.0	2.4	_	
				I _{OH} = -24 mA	3.0	2.2	_	
	L-level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 100 μA	2.3 to 3.6	_	0.2	
				I _{OL} = 8 mA	2.3	_	0.6	
				I _{OL} = 12 mA	2.7	_	0.4	
				I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 5.5 V		2.3 to 3.6	_	±5.0	μA
2 state sutput OEE sta	to ourropt	1	$V_{IN} = V_{IH} \text{ or } V_{IL}$		2.3 to 3.6	_	±5.0	
3-state output OFF state current		loz	V _{OUT} = 0 to 5.5 V		2.3 10 3.0		±5.0	μA
Power-off leakage current		IOFF	$V_{IN}/V_{OUT} = 5.5 V$		0		10.0	μA
Quiescent supply curre	ont	Icc	V _{IN} = V _{CC} or GND		2.3 to 3.6		20.0	
		100	$V_{IN}/V_{OUT} = 3.6$ to 5.5 \	/	2.3 to 3.6	—	±20.0	μA
Increase in Icc per input	ut	ΔI_{CC}	$V_{IH} = V_{CC} - 0.6 \ V$		2.3 to 3.6	—	500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Symbol Test Condition T				Max	Unit
Characteristics	Symbol	Test Condition	V _{CC} (V)	CL(pF)	Min	wax	Unit
	+		2.5 ± 0.2	30	1.5	5.4	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	50	1.5	5.3	ns
	t _{pHL}		3.3 ± 0.3	50	1.5	4.5	
3-state output enable time	+	Figure 1, Figure 3	2.5 ± 0.2	30	1.5	7.0	
	t _{pZL}		2.7	50	1.5	6.0	ns
	^t pZH		3.3 ± 0.3	50	1.5	5.4	
			2.5 ± 0.2	30	1.5	6.4	
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	50	1.5	5.4	ns
	^t pHZ		3.3 ± 0.3	50	1.5	5.3	
			2.5 ± 0.2	30	_	—	
Output to output skew	t _{osLH}	(Note)	2.7	50		_	ns
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$	50		1.0	

Note: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	V_{IH} = 2.5 V, V_{IL} = 0 V, C_L =30pF	2.5	0.6	V
	VOLP	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}, C_L = 50 \text{pF}$	3.3	0.8	v
Quiet output minimum dynamic V _{OL}	IVolvI	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}, C_L = 30 \text{pF}$	2.5	0.6	V
		$V_{IH}=3.3$ V, $V_{IL}=0$ V, C_L =50pF	3.3	0.8	

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	C _{OUT}		3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Not	e) 3.3	25	pF

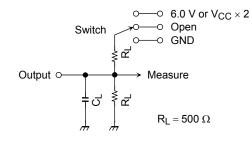
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16$ (per bit)

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AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
t _{pLZ} , t _{pZL}	$\begin{array}{c} \text{6.0 V} \\ \text{V}_{\text{CC}} \times 2 \end{array}$	$@V_{CC} = 3.3 \pm 0.3 \text{ V} \\ @V_{CC} = 2.5 \pm 0.2 \text{ V} \\ \label{eq:V_CC}$	
t _{pHZ} , t _{pZH}	GND		



AC Waveform

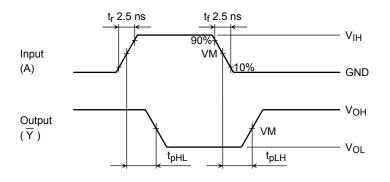
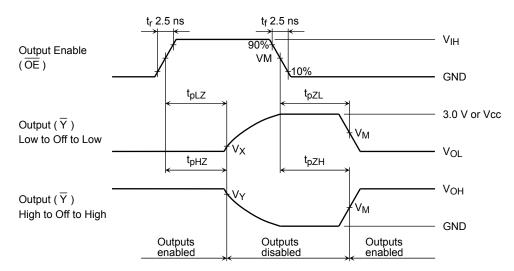
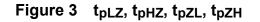


Figure 2 t_{pLH}, t_{pHL}





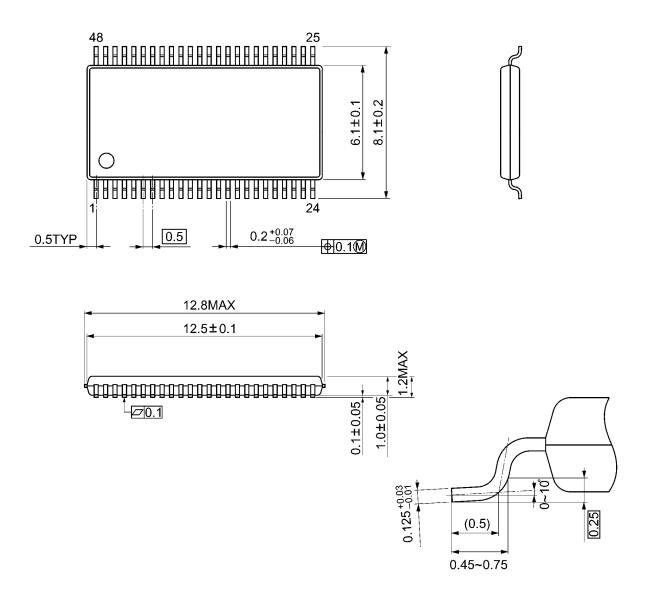
Symbol	V _{CC}			
Symbol	$3.3\pm0.3\;V$	2.7 V	$2.5\pm0.2\;V$	
VIH	2.7 V	2.7 V	V _{CC}	
VM	1.5 V	1.5 V	V _{CC} /2	
VX	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V	
VY	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 0.15 V	



Package Dimensions

TSSOP48-P-0061-0.50A

Unit: mm



Weight: 0.25 g (typ.)

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20070701-EN GENERAL

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